

10/591352  
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**INFORMATION  
DISCLOSURE STATEMENT  
TRANSMITTAL**

**To Commissioner For Patents**

Enclosed herewith is a Form PTO-1449, any required copies of documents listed thereon, and any concise explanation of their relevance is indicated below per 37 CFR 1.97.

<b>Application Number</b>	10591352
<b>Filing Date</b>	8/31/2006
<b>First Named Inventor</b>	KOOPS, GERRIT, E., J.
<b>Group Art Unit</b>	2812
<b>Examiner Name</b>	/Thu Huong Dinh/
<b>Atty. Docket Number</b>	GB04 0056US1

**U.S. PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Document Number No.-Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear
/T.D./	1	US- 5 637 898	06/10/1997	BALIGA BANTVAL J.	
		US-			

**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Document Number (ctry <sup>2</sup> -no. <sup>4</sup> -kind <sup>5</sup> , if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of cited document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear
/T.D./	1	WO 01/09956	02/08/2001	LARIK, JOOST ET AL.	

**NON-PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in capital letters), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	
/T.D./	1	LIN M-J ET AL: "CHARACTERIZING TRENCH-GATE POWER METAL-OXIDE-SEMICONDUCTOR FIELD EFFECT TRANSISTOR WITH MULTI-LAYER DIELECTRICS AT THE TRENCH BOTTOM"; JAPANESE JOURNAL OF APPLIED PHYSICS, PART 1; VOL. 42 NO. 11; NOV. 2003; TOKYO JP PP 6795-6799.	

<b>Examiner Signature</b>	/Thu Huong Dinh/	<b>Date Considered</b>	09/06/2007
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\* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup>Unique citation designation number. <sup>2</sup>See attached Kinds of U.S. Patent Documents. <sup>3</sup>Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup>For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the